



Small Signal Schottky Barrier Diode

Features

- · Integrated protection ring against static discharge
- Very low forward voltage

Applications

Applications where a very low forward voltage is required



Mechanical Data

Case: MicroMELF Glass Case

Weight: approx. 12 mg Cathode Band Color: Black **Packaging Codes/Options:**

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box GS08 / 2.5 k per 7" reel (8 mm tape), 12.5 k/box

Parts Table

Part	Type differentiation	Ordering code	Remarks
BAS385	V _R = 30 V	BAS385-GS18 or BAS385-GS08	Tape and Reel

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_{R}	30	V
Peak forward surge current	t _p = 10 ms	I _{FSM}	5	Α
Repetitive peak forward current	t _p ≤ 1 s	I _{FRM}	300	mA
Forward current		I _F	200	mA
Average forward current	V _{RWM} = 25 V	I _{FAV}	200	mA

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction ambient	on PC board 50 mm x 50 mm x 1.6 mm	R_{thJA}	320	K/W
Junction temperature		T _j	125	°C
Storage temperature range		T _{stg}	- 65 to + 150	°C

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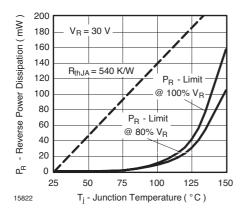


Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward voltage	I _F = 0.1 mA	V _F			240	mV
	I _F = 1 mA	V _F			320	mV
	I _F = 10 mA	V _F			400	mV
	I _F = 30 mA	V _F			500	mV
	I _F = 100 mA	V _F			800	mV
Reverse current	$V_R = 25 \ V, t_p = 300 \ \mu s$	I _R			2.3	μΑ
Diode capacitance	V _R = 1 V, f = 1 MHz	C _D			10	pF

Typical Characteristics ($T_{amb} = 25$ °C unless otherwise specified)



T_j = 150 °C

T_j = 150 °C

T_j = 25 °C

T_j = 25 °C

O.1

0.1

0.5

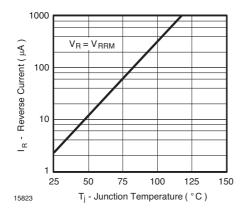
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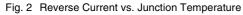
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V_F - Forward Voltage (V)

Fig. 1 Max. Reverse Power Dissipation vs. Junction Temperature

Fig. 3 Forward Current vs. Forward Voltage





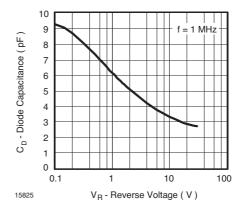


Fig. 4 Diode Capacitance vs. Reverse Voltage





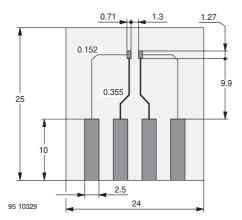
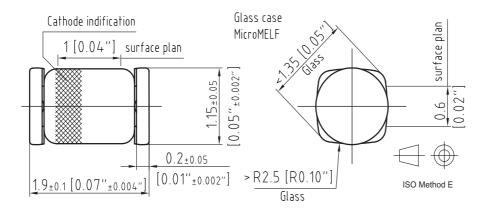
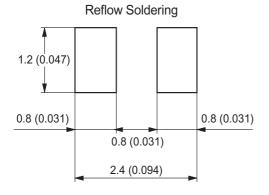


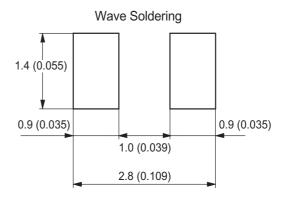
Fig. 5 Board for R_{thJA} definition (in mm)

Package Dimensions in mm



9612072





BAS385

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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